NSN 5961-00-824-5184

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View Online at https://aerobasegroup.com/nsn/5961-00-824-5184
Inclosure Material: Metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
0.230 inches
Internal Configuration:
Field effect
Electrode Internally-electrically Connected To Case:
Gate
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
50.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source
Current Rating Per Characteristic:
100.00 milliamperes gate current
Power Rating Per Characteristic:
350.0 milliwatts total device dissipation
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius case
Terminal Type And Quantity:
3 uninsulated wire lead
Specification Data:
80131-release4584 professional/industrial association specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0